



3.3V CMOS OCTAL TRANSPARENT D-TYPE LATCH WITH 3-STATE OUTPUTS, 5 VOLT TOLERANT I/O AND BUS-HOLD

IDT74LVCH2573A

FEATURES:

- 0.5 MICRON CMOS Technology
- ESD > 2000V per MIL-STD-883, Method 3015;
> 200V using machine model (C = 200pF, R = 0)
- 1.27mm pitch SOIC, 0.65mm pitch SSOP,
0.635mm pitch QSOP, 0.65mm pitch TSSOP packages
- Extended commercial range of -40°C to +85°C
- V_{CC} = 3.3V ± 0.3V, Normal Range
- V_{CC} = 2.3V to 3.6V, Extended Range
- CMOS power levels (0.4µW typ. static)
- Rail-to-Rail output swing for increased noise margin
- All inputs, outputs and I/O are 5 Volt tolerant
- Supports hot insertion

Drive Features for LVCH2573A:

- Balanced Output Drivers: ±12mA
- Low switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- Data communication and telecommunication systems

DESCRIPTION:

The LVCH2573A octal transparent D-type latch is built using advanced dual metal CMOS technology. The device features 3-state outputs de-

signed specifically for driving highly capacitive or relatively low-impedance loads, and is particularly suitable for implementing buffer registers, input-output (I/O) ports, bidirectional bus drivers, and working registers.

While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels at the D inputs.

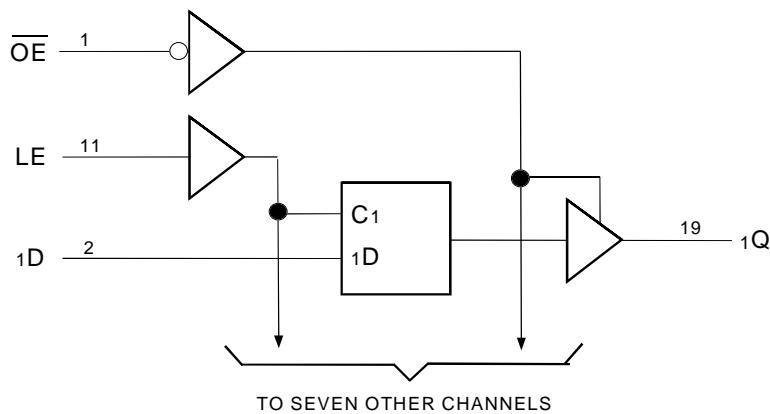
A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components. \overline{OE} does not affect the internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

The LVCH2573A has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been developed to drive ±12mA at the designated thresholds.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

The LVCH2573A has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

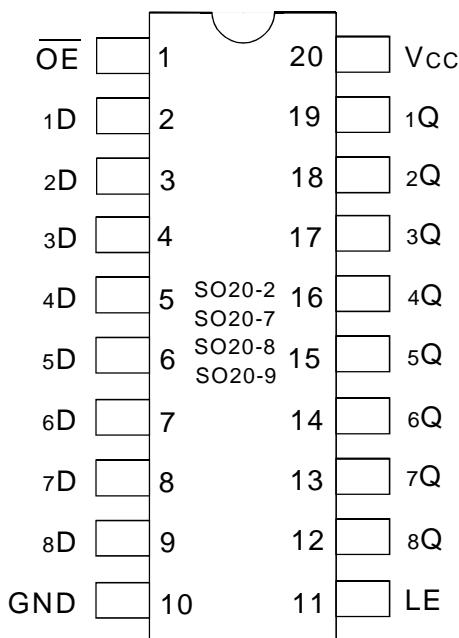
FUNCTIONAL BLOCK DIAGRAM



EXTENDED COMMERCIAL TEMPERATURE RANGE

FEBRUARY 2000

PIN CONFIGURATION



SOIC/ SSOP/ QSOP/ TSSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max.	Unit
VTERM	Terminal Voltage with Respect to GND	- 0.5 to +6.5	V
TSTG	Storage Temperature	- 65 to +150	°C
I _{OUT}	DC Output Current	- 50 to +50	mA
I _{IK}	Continuous Clamp Current, V _I < 0 or V _O < 0	- 50	mA
I _{CC}	Continuous Current through each V _{CC} or GND	±100	mA
I _{SS}			

8LVC

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	4.5	6	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	5.5	8	pF
C _{I/O}	I/O Port Capacitance	V _{IN} = 0V	6.5	8	pF

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NOTE:

- As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description
OE	Output-enable Input (Active LOW)
LE	Latch-enable Input
x _D	Data Inputs ⁽¹⁾
x _Q	3-State Outputs

NOTE:

- These pins have "Bus-hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (each latch)⁽¹⁾

Inputs			Outputs
OE	LE	x _D	x _Q
L	H	H	H
L	H	L	L
L	L	X	Q ₀
H	X	X	Z

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High-Impedance
- Q₀ = Level of Q before the indicated steady-state input conditions were established.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C To +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	VCC = 2.3V to 2.7V		1.7	—	—	V
		VCC = 2.7V to 3.6V		2	—	—	
VIL	Input LOW Voltage Level	VCC = 2.3V to 2.7V		—	—	0.7	V
		VCC = 2.7V to 3.6V		—	—	0.8	
I _{IH} I _{IL}	Input Leakage Current ⁽³⁾	VCC = 3.6V	V _I = 0 to 5.5V	—	—	±5	µA
I _{OZH} I _{OZL}	High Impedance Output Current (3-State Output pins)	VCC = 3.6V	VO = 0 to 5.5V	—	—	±10	µA
I _{OFF}	Input/Output Power Off Leakage	VCC = 0V, V _{IN} or VO ≤ 5.5V		—	—	±50	µA
V _{IK}	Clamp Diode Voltage	VCC = 2.3V, I _{IN} = -18mA		—	-0.7	-1.2	V
V _H	Input Hysteresis	VCC = 3.3V		—	100	—	mV
I _{CCL} I _{CCH} I _{CCZ}	Quiescent Power Supply Current	VCC = 3.6V	V _{IN} = GND or VCC	—	—	10	µA
			3.6 ≤ V _{IN} ≤ 5.5V ⁽²⁾	—	—	10	
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at VCC - 0.6V, other inputs at VCC or GND VCC = 3.0 – 3.6V		—	—	500	µA

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NOTES:

1. Typical values are at VCC = 3.3V, +25°C ambient.
2. This applies in the disabled state only.
3. Per control input. Excludes Bus-Hold current.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
I _{BHH} I _{BHL}	Bus-Hold Input Sustain Current	VCC = 3.0V	V _I = 2.0V	-75	—	—	µA
			V _I = 0.8V	75	—	—	
I _{BHH} I _{BHL}	Bus-Hold Input Sustain Current	VCC = 2.3V	V _I = 1.7V	—	—	—	µA
			V _I = 0.7V	—	—	—	
I _{BHOO} I _{BHLO}	Bus-Hold Input Overdrive Current	VCC = 3.6V	V _I = 0 to 3.6V	—	—	±500	µA

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NOTES:

1. Pins with Bus-hold are identified in the pin description.
2. Typical values are at VCC = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
VOH	Output HIGH Voltage	VCC = 2.3V to 3.6V	I _{OH} = - 0.1mA	VCC - 0.2	—	V
		VCC = 2.3V	I _{OH} = - 4mA	1.9	—	
			I _{OH} = - 6mA	1.7	—	
		VCC = 2.7V	I _{OH} = - 4mA	2.2	—	
			I _{OH} = - 8mA	2	—	
		VCC = 3.0V	I _{OH} = - 6mA	2.4	—	
			I _{OH} = - 12mA	2	—	
VOL	Output LOW Voltage	VCC = 2.3V to 3.6V	I _{OL} = 0.1mA	—	0.2	V
		VCC = 2.3V	I _{OL} = 4mA	—	0.4	
			I _{OL} = 6mA	—	0.55	
		VCC = 2.7V	I _{OL} = 4mA	—	0.4	
			I _{OL} = 8mA	—	0.6	
		VCC = 3.0V	I _{OL} = 6mA	—	0.55	
			I _{OL} = 12mA	—	0.8	

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NOTE:

1. V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = - 40°C to +85°C.

SWITCHING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	V _{CC} = 2.5V ± 0.2V		V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{PHL}	Propagation Delay xD to xQ	—	—	1.5	9	1.5	8	ns
t _{TPLH}	Propagation Delay LE to xQ	—	—	1.5	9.5	1.5	8.5	ns
t _{TPZH}	Output Enable Time OE to xQ	—	—	1.5	9.5	1.5	8.5	ns
t _{TPLZ}	Output Disable Time OE to xQ	—	—	1.5	7	1.5	6.5	ns
t _W	Pulse Duration, LE HIGH	—	—	3.3	—	3.3	—	ns
t _{SU}	Setup Time, data before LE↓	—	—	2.5	—	2.5	—	ns
t _H	Hold Time, data after LE↓	—	—	1.5	—	1.5	—	ns
t _{SK(0)}	Output Skew ⁽²⁾	—	—	—	—	—	500	ps

NOTES:

1. See test circuits and waveforms. T_A = - 40°C to +85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

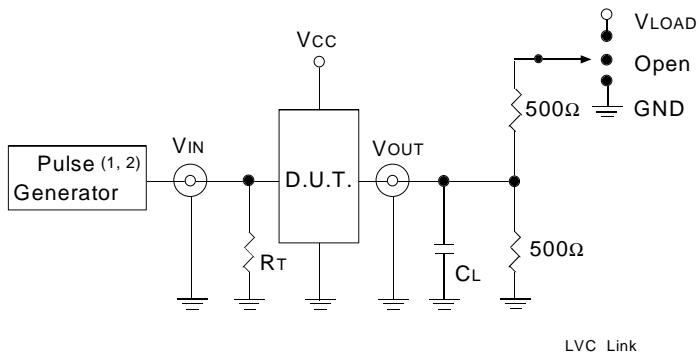
TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$V_{CC(1)} = 3.3V \pm 0.3V$	$V_{CC(1)} = 2.7V$	$V_{CC(2)} = 2.5V \pm 0.2V$	Unit
V_{LOAD}	6	6	$2 \times V_{CC}$	V
V_{IH}	2.7	2.7	V_{CC}	V
V_T	1.5	1.5	$V_{CC}/2$	V
V_{LZ}	300	300	150	mV
V_{HZ}	300	300	150	mV
C_L	50	50	30	pF

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TEST CIRCUITS FOR ALL OUTPUTS



DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.
 RT = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

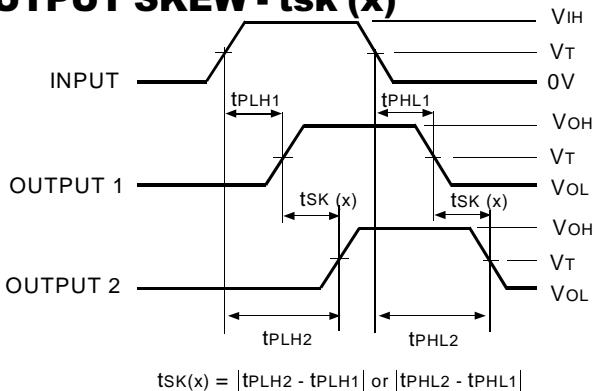
1. Pulse Generator for All Pulses: Rate $\leq 10\text{MHz}$; $t_f \leq 2.5\text{ns}$; $t_r \leq 2.5\text{ns}$.
2. Pulse Generator for All Pulses: Rate $\leq 10\text{MHz}$; $t_f \leq 2\text{ns}$; $t_r \leq 2\text{ns}$.

SWITCH POSITION

Test	Switch
Open Drain	V_{LOAD}
Disable Low	
Enable Low	
Disable High	GND
Enable High	
All Other tests	Open

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OUTPUT SKEW - $t_{SK}(x)$

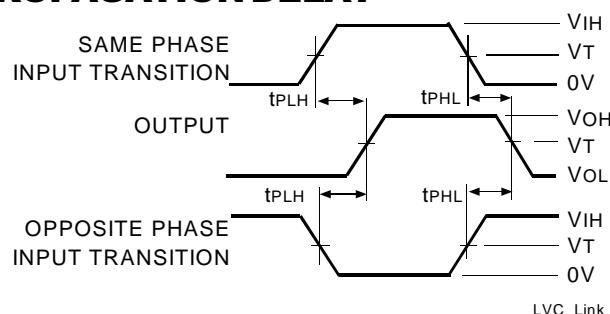


$$tsk(x) = |tPLH2 - tPLH1| \text{ or } |tPHL2 - tPHL1|$$

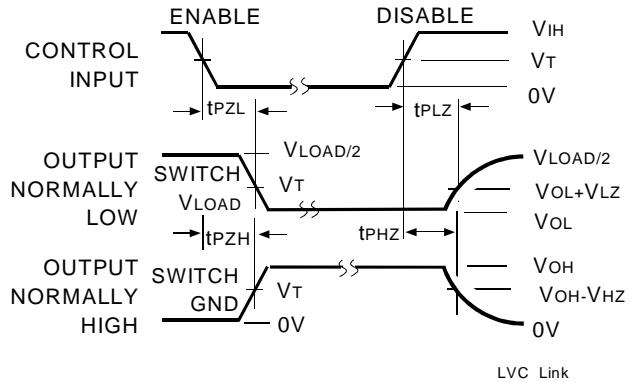
NOTES:

1. For $tsk(o)$ OUTPUT1 and OUTPUT2 are any two outputs.
2. For $tsk(b)$ OUTPUT1 and OUTPUT2 are in the same bank.

PROPAGATION DELAY



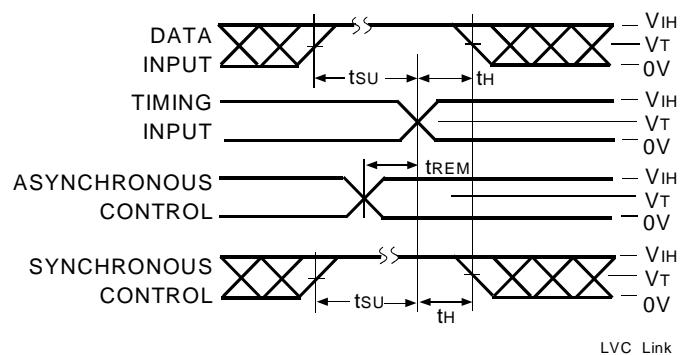
ENABLE AND DISABLE TIMES



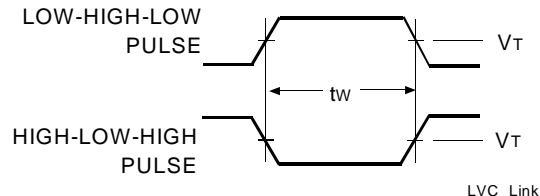
NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD, AND RELEASE TIMES



PULSE WIDTH



ORDERING INFORMATION

IDT	XX	LVC	X	XXXX	XX	
Temp. Range		Bus-Hold		Device Type	Package	
					SO	Small Outline IC (gull wing) (SO20-2)
					PY	Shrink Small Outline Package (SO20-7)
					Q	Quarter Size Small Outline Package (SO20-8)
					PG	Thin Shrink Small Outline Package (SO20-9)
				2573A		Octal Transparent D-Type Latch with 3-State Outputs, ±12mA
			H			Bus-hold
				74		-40°C to +85°C



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